

Product / Process Change Notice

No.: Z200-PCN-DM201608-03-A

Date: 08/24/2016

Change Title : <u>W25Q80JV "J-Series" (58nm) to replace W25Q80DV "D-Series" (90nm) 8Mb SpiFlash®</u> Memories

Change Classification: ☑ Major □ Minor

Change item : Design D Raw Material D Wafer FAB Assembly D Packing D Testing D Others

Affected Product(s) :

W25Q80DVSNIG, W25Q80DVSSIG, W25Q80DVSVIG, W25Q80DVZPIG, W25Q80DVUXIE

Description of Change(s)

The W25Q80JV 8Mb SpiFlash® Memories use Winbond's 58nm Flash technology. It is function-compatible with W25Q80DV 90nm devices offering improved performance, features and availability. (refer the Attachment I)

Reason for Change(s) :

Improve features and Command backward compatible with W25Q80DV.

Impact of Change(s) : (positive & negative)

Form: No Change		
Fit: No Change		
Function : No Concern	(Please refe	r to attachment I)
Reliability : No Concern	(Please refe	r to attachment II)
Hazardous Substances:	No Concern	(Please refer to attachment III)

Qualification Plan/ Results :

Based on Winbond W25Q80JV Serial Flash Reliability report, the new product meets our criteria and no quality concern (refer to Attachment II in details)

Implementation Plan :

Please refer to Attachment IV for details.

Date Code:	onward 🛛 Lot No:	onward	☑ Proposed first ship date: <u>Refer to Attachment IV in details</u>
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Originator: (QA)	Hyhuang		Approval: (QA Dept. Manager)	y H Chang	Approval: (QRA Director)	Chon
Contact for Questions Address : & Concerns				<u>6-3-5678168</u> (ext. nxing Rd., Jhubei (nd.com		



Customer Comments:

Note: Please sign this notice, and return to Winbond contact within **30** days. If no response is received within **30** days, this Change Request will be assumed to meet your approval.

Approval	Disapproval	Conditional Approval :
Comment:		
Data		
Date:		_
Dept. name:		
Person in charge:		



Winbond Electronics Corporation

6F., No.38, Gaotie 1st Rd., Jhubei City, Hsinchu County 30273, Taiwan R.O.C.

Affected Products

As below:

Winbond Current PN	Winbond Primary Replacement PN	
(90nm D-Series)	(58nm J-Series)	
W25Q80DVSNIG	W25Q80JVSNIQ	
W25Q80DVSSIG	W25Q80JVSSIQ	
W25Q80DVSVIG	W25Q80JVSVIQ	
W25Q80DVZPIG	W25Q80JVZPIQ	
W25Q80DVUXIE	W25Q80JVUXIQ	



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Product Obsolescence Notice

W25Q80JV SpiFlash Memories

Notification Date: August, 16, 2016

Dear Valued Customer,

This letter is to notify you of Winbond's intention to terminate production of the W25Q80DV SpiFlash memory, and replace it with the W25Q80JV. Replacement part numbers are listed below:

Winbond Current PN	Winbond Primary Replacement PN	
(90nm D-Series)	(58nm J-Series)	
W25Q80DVSNIG	W25Q80JVSNIQ	
W25Q80DVSSIG	W25Q80JVSSIQ	
W25Q80DVSVIG	W25Q80JVSVIQ	
W25Q80DVZPIG	W25Q80JVZPIQ	
W25Q80DVUXIE	W25Q80JVUXIQ	

The W25Q80JV device features:

Features

- a) Command backward compatible with W25Q80DV (same Superset Instruction Set)
- b) Clock operation up to 133MHz
- c) Lower power consumption
- d) SPI with Single / Dual / Quad
- e) Flexible architecture with 4KB sectors

Please refer to the table below for your particular product last time order date and Winbond last shipment date and use

this table to determine your last time buys and subsequent request dates. Winbond Electronics reserves the right to limit last time buy quantities based on capacity and material availability. Please notify Winbond as soon as possible if there are any concerns with these this schedule.

Part	Notification	Last Order	Last Ship	Part	Reliability	Mass
Number	Date	Date	Date	Number	Report	Production
W25Q80DV	Aug./16/ 2016	Feb./16/ 2017	Aug./16/ 2017	W25Q16JV	Aug./15/ 2016	May/12/ 2016

Eddy Hung

Eddy Hung Assistant Vice President of Flash Marketing